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December 2010

FAN2013B — 2A Low-Voltage, Current-Mode Synchronous PWM Buck Regulator

Features

- 95% Efficiency, Synchronous Operation
- Adjustable Output Voltage from 0.8V to 2.5V
- 4.5V to 5.5V Input Voltage Range
- Up to 2A Output Current
- Fixed-Frequency 1.2 MHz PWM Operation
- Soft-Start Function
- Excellent Load Transient Response
- Power-Good Flag
- Over-Voltage, Under-Voltage Lockout, Short-Circuit, and Thermal Shutdown Protections
- 3x3mm 6-Lead MLP Package

Applications

- Hard Disk Drive
- Set-Top Box
- Point-of-Load Power
- Notebook Computer
- Communications Equipment

Description

The FAN2013B is a high-efficiency, low-noise, synchronous Pulse Width Modulated (PWM) current-mode DC-DC converter designed for low-voltage applications. It provides up to 2A continuous-load current from the 4.5V to 5.5V input. The output voltage is adjustable over a wide range by means of an external voltage divider.

The FAN2013B is enabled when the input voltage on the V_{IN} pin exceeds the UVLO threshold.

A current-mode control loop with a fast transient response ensures excellent line and load regulation. The fixed 1.2MHz switching frequency enables designers to choose a small, inexpensive external inductor and capacitor. Filtering can be accomplished with small components, reducing space and cost.

Protection features include input under-voltage lockout, short-circuit protection, and thermal shutdown. Soft-start limits inrush current during start-up conditions.

The device is available in a 3x3mm 6-lead MLP.

Typical Application

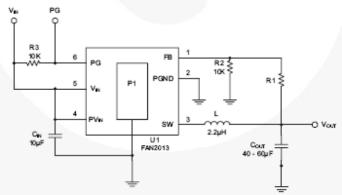


Figure 1. Typical Application

Ordering Information

Part Number	Output Voltage	Package	Packing Method
FAN2013BMPX	0.8V to 2.5V	3x3mm 6-Lead Molded Leadless Package (MLP)	Tape and Reel

Pin Assignments

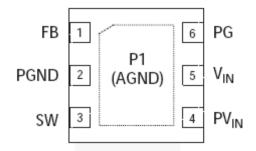


Figure 2. Pin Assignments (Top View)

Pin Definitions

Pin#	Name	Description
P1	AGND	Analog Ground. P1 must be soldered to the PCB ground.
1	FB	Feedback Input. Adjustable voltage option; connect this pin to the resistor divider.
2	PGND	Power Ground . This pin is connected to the internal MOSFET switches. This pin must be externally connected to AGND.
3	SW	Switching Node. This pin is connected to the internal MOSFET switches.
4	PVIN	Supply Voltage Input. This pin is connected to the internal MOSFET switches.
5	VIN	Supply Voltage Input.
6	PG	Open Drain Power Good.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
V _{IN}	Supply Voltage		-0.3	7.0	V
	Input Voltage on PVIN and Any Other	er Pin	-0.3	V _{IN}	V
$\theta_{\sf JC}$	Thermal Resistance, Junction-to-Tab ⁽¹⁾			8	°C/W
TL	Lead Soldering Temperature (10 Seconds)			+260	°C
T _{STG}	Storage Temperature		-65	+150	°C
TJ	Junction Temperature		-40	+150	°C
ESD	Electrostatic Discharge Protection	Human Body Model, JESD22-A114	3.5		147
ESD	Level ⁽²⁾	Charged Device Model, JESD22-C101	2.0		kV

Notes:

- Junction-to-ambient thermal resistance, θ_{JA}, is a strong function of PCB material, board thickness, thickness and number of copper planes, number of via used, diameter of via used, available copper surface, and attached heat sink characteristics.
- 2. Using Mil Std. 883E, method 3015.7 (Human Body Model) and EIA/JESD22C101-A (Charged Device Model).

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbols	Parameter	Min.	Тур.	Max.	Unit
V _{IN}	V _{IN} Supply Voltage Range		1	5.5	V
V _{OUT}	V _{OUT} Output Voltage Range, Adjustable Version			2.5	V
l _{out}	I _{OUT} Output Current		//	2.0	Α
L Inductor ⁽³⁾			2.2		μH
C _{IN} Input Capacitor ⁽³⁾		10	20	y	μF
C _{OUT}	Output Capacitor ⁽³⁾	20	40	y	μF
T _A	T _A Operating Ambient Temperature Range			+85	°C

Note:

3. Refer to the Applications section for details.

Electrical Characteristics

 V_{IN} = 4.5V to 5.5V, V_{OUT} = 1.2V, I_{OUT} = 200mA, C_{IN} = 10 μ F, C_{OUT} = 40 μ F, L = 2.2 μ H, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = 25°C.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{IN}	Input Voltage		4.5		5.5	V
IQ	Quiescent Current	I _{OUT} = 0mA		10	16	mA
\/	UVLO Threshold	V _{IN} Rising	3.4	3.7	4.0	V
V_{UVLO}	OVEO Tillesiloid	Hysteresis		150		mV
R _{ON_PMOS}	PMOS On Resistance	$V_{IN} = V_{GS} = 5V$		90		mΩ
Ron_nmos	NMOS On Resistance	V _{IN} = V _{GS} = 5V		90		mΩ
I _{LIMIT}	P-Channel Current Limit	4.5V < V _{IN} < 5.5V	2.8	3.5	4.2	Α
	Over Temperature Dretection	Rising Temperature		150		°C
	Over-Temperature Protection	Hysteresis		20		°C
f _{SW}	Switching Frequency		1000	1200	1400	kHz
R _{LINE}	Line Regulation	V _{IN} = 4.5 to 5.5V, I _{OUT} = 100mA		0.16		%/V
R _{LOAD}	Load Regulation	$0mA \leq I_{OUT} \leq 2000mA$		0.3	0.6	%
V	Output Voltage During Load	I_{OUT} from 1500mA to 100mA, C_{OUT} = 60 μ F			5	%
V _{OUT}	Output Voltage During Load Transition ⁽⁴⁾	I_{OUT} from 100mA to 1500mA, C_{OUT} = 60 μ F	-5			%
I _{LEAK}	Reverse Leakage Current into Pin SW	V _{IN} = Open, EN = GND, V _{SW} = 5.5V		0.1	1.0	μΑ
V _{REF}	Reference Voltage			0.8		V
V _{OUT} Out	Output Voltage Accuracy	V_{IN} = 4.5 to 5.5V, 0mA \leq I _{OUT} \leq 2000mA, T _A = 0°C to +85°C	-2		2	%
		V _{IN} = 4.5 to 5.5V, 0mA ≤ I _{OUT} ≤ 2000mA, T _A = -40°C to +85°C	-3		3	%
	Power Good Output Threshold and Hysteresis	FB Voltage Rising		0.9xV _{OUT}		V
		Hysteresis		1		%
t _{PG}	Power Good Output Delay			100		μs
V_{PG_LOW}	Power Good Voltage Low	I _{sink} =6mA, Open-Drain Output			0.4	V
\/	Over-Voltage Protection	FB Voltage Rising		1.07 xV _{OUT}		V
V_{OVP}	Threshold and Hysteresis	Hysteresis		2		%

Note:

4. Please refer to the load transient response test waveform shown in Figure 3.

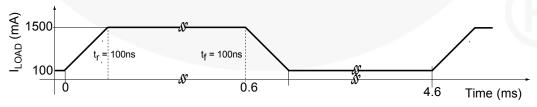
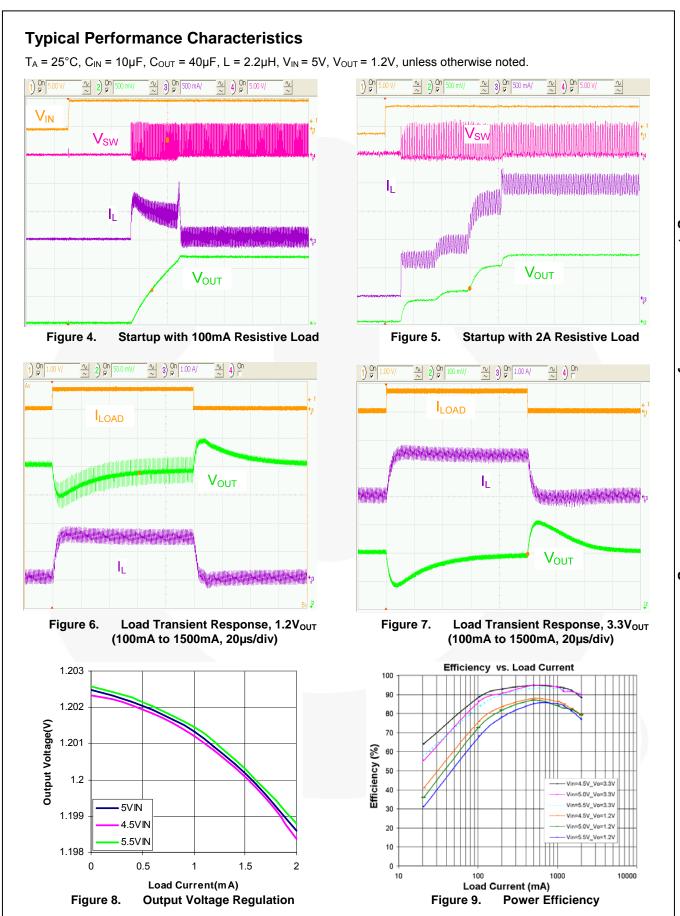


Figure 3. Load Transient Response Test Waveform



Block Diagram

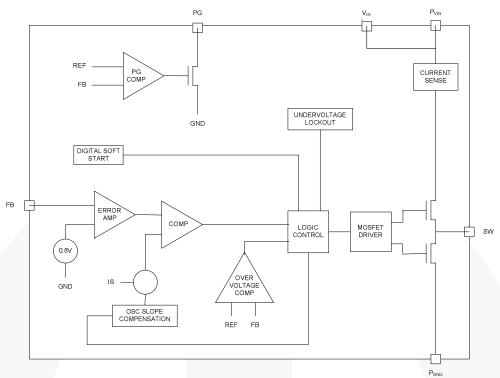


Figure 10. Block Diagram

Detailed Operation Description

The FAN2013B is a step-down pulse-width modulated (PWM) current mode converter with a fixed switching frequency of 1.2MHz. At the rising edge of each clock cycle, the P-channel transistor is turned on until the PWM comparator trips or the current limit is reached. During the ON time, the inductor current ramps up and is monitored by the internal current-mode control loop. After a minimum dead time, the N-channel transistor is turned ON and the inductor current ramps down. As the clock cycle is completed, the N-channel switch is turned OFF and the next clock cycle starts. The duty cycle is given by the ratio of output voltage and input voltage. The converter runs at minimum duty cycle when the output voltage is at minimum and input voltage is at maximum. The duty cycle increases proportionally as the input voltage approaches the output voltage.

UVLO and Soft-Start

The internal voltage reference, V_{REF} , and the IC remain reset until V_{IN} reaches the UVLO threshold.

The FAN2013B has an internal soft-start circuit that limits the inrush current during start-up. This prevents possible voltage drops of the input voltage and eliminates the output voltage overshoot. The soft-start is implemented as a digital circuit, increasing the switch current in four steps to the P-channel current limit. Typical start-up time for a 40µF output capacitor with a load current of 2.0A is 800µs.

Output Over-Voltage Protection

When output voltage, V_{OUT} , reaches approximately 7% above the nominal value, the device turns OFF the P-channel switch and turns ON part of the N-channel transistor with a built-in current limit of about 400mA. When V_{OUT} reaches the hysteresis of about 2%, the device starts switching normally in closed loop. If output voltage is pulled up by an external voltage source with a current limit higher than typical 400mA, the output voltage stays up at the external voltage source level.

The over-voltage protection is designed to limit the output voltage excursion in case of a transient response from full load to a minimum load.

Output Short-Circuit Protection

The switch peak current is limited cycle by cycle to a typical value of 3.5A. In the event of an output voltage short circuit, the device operates with a frequency of 400kHz and minimum duty cycle, making the average typical input current 0.45A.

Thermal Shutdown

When the die temperature exceeds 150°C, a reset occurs and remains in effect until the die cools to 130°C, when the circuit is allowed to re-initiate a soft-start cycle..

Applications Information

Setting the Output Voltage

The internal voltage reference is 0.8V. The output is divided down by a voltage divider, R1 and R2 to the FB pin. The output voltage is:

$$V_{OUT} = V_{REF} \left(1 + \frac{R_1}{R_2} \right)$$
 (2)

According to this equation, assuming desired output voltage of 1.2V, and given R2 = $10 \text{K}\Omega$ as the recommended resistance for any output voltage setting, the calculated value of R1 is $5 \text{K}\Omega$. Maximum V_{OUT} = 2.5V.

Inductor Selection

The inductor parameters directly related to device performance are saturation current and DC resistance. The FAN2013B operates with a typical inductor value of $2.2\mu H$. The lower the DC resistance, the higher the efficiency. For saturation current, the inductor should be rated higher than the maximum load current, plus half of the inductor ripple current, calculated by:

$$\Delta^{I}_{L} = V_{OUT} \times \frac{1 - (V_{OUT} / V_{IN})}{L \times f}$$
 (3)

where:

 ΔI_L = Inductor Ripple Current

f = Switching Frequency

L = Inductor Value

Recommended inductors are listed in Table1.

Table 1. Recommended Inductors

Inductor Value	Vendor	Part Number
2.2µH	Coiltronics	SD25 2R2
2.2µH	Murata	LQH66SN2R2M03L

Capacitor Selection

For best performance, a low-ESR input capacitor is required. A ceramic capacitor of at least $10\mu F$, placed as close to the V_{IN} and AGND pins as possible is recommended.

The output capacitor determines the output ripple and the transient response. A minimum of $20\mu F$ output capacitor is required for the FAN2013B to operate in stable conditions.

Table 2. Recommended Capacitors

Capacitor Value	Vendor	Part Number
	Taiyo Yuden	JMK212BJ106MG
	Talyo Tudeli	JMK316BJ106KL
10μF	TDK	C2012X5ROJ106K
	IDK	C3216X5ROJ106M
	Murata	GRM32ER61C106K

PCB Layout Recommendations

The inherently high peak currents and switching frequency of power supplies require a careful PCB layout design. For best results, use wide traces for high-current paths and place the input capacitor, the inductor, and the output capacitor as close as possible to the integrated circuit terminals. To minimize voltage stress to the device resulting from ever-present switching spikes, use an input bypass capacitor with low ESR. Note that the peak amplitude of the switching spikes depends upon the load current; the higher the load current, the higher the switching spikes.

The resistor divider that sets the output voltage should be routed away from the inductor to avoid RF coupling. The ground plane at the bottom side of the PCB acts as an electromagnetic shield to reduce EMI. The recommended PCB layout is shown below in Figure 11.

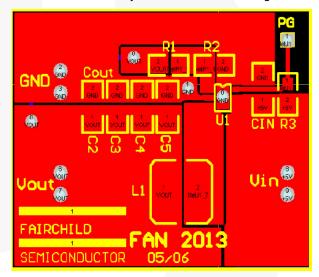
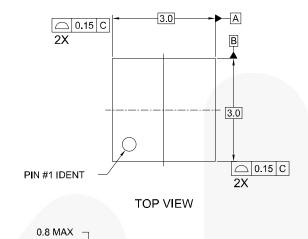
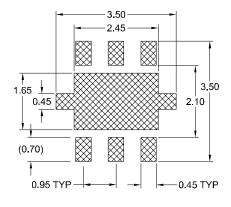


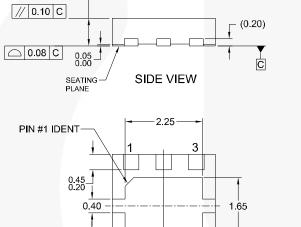
Figure 11. Recommended PCB Layout

Physical Dimensions





RECOMMENDED LAND PATTERN



BOTTOM VIEW

NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-229, VARIATION WEEA, DATED 11/2001 EXCEPT FOR DAP EXTENSION TABS
- B. DIMENSIONS ARE IN MILLIMETERS.

0.2 MIN

C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994

0.95

MLP06FrevA

Figure 12. 3x3mm 6-Lead Molded Leadless Package (MLP)

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